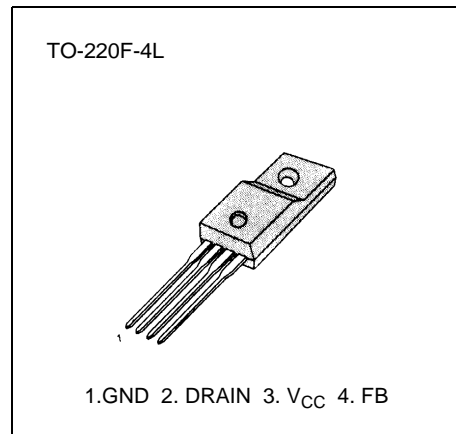


**SPS**

The SPS product family is specially designed for an off-line SMPS with minimal external components. The SPS consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry. Compared to discrete MOSFET and controller or RCC switching converter solution, a SPS can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.



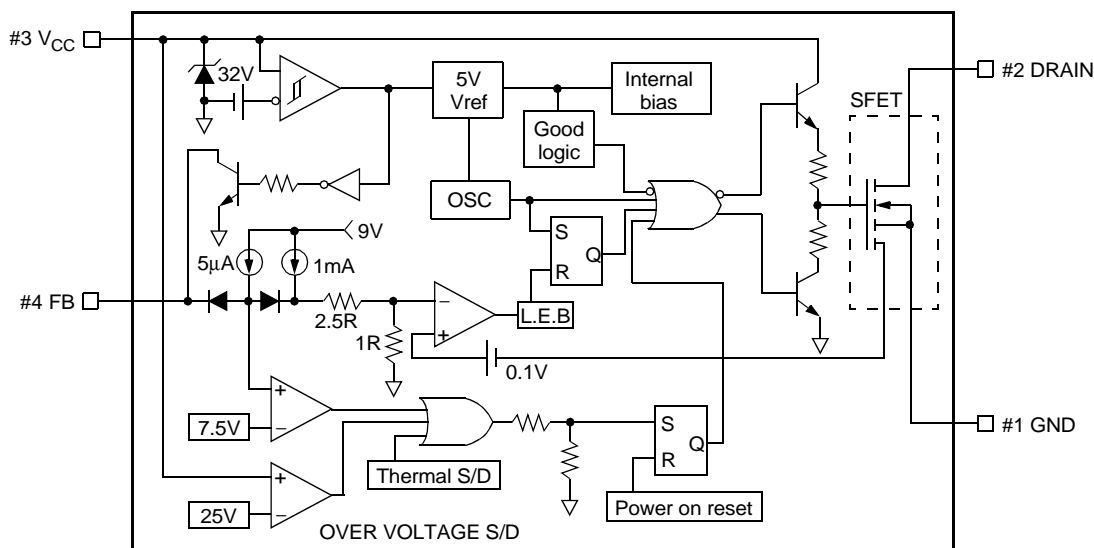
**FEATURES**

- Precision fixed operating frequency (100kHz)
- Pulse by pulse over current limiting
- Over Current Protection
- Over Voltage Protection (Min. 23V)
- Internal thermal shutdown function
- Under voltage lockout
- Internal high voltage sense FET
- Auto restart

**ORDERING INFORMATION**

Device	Package	Operating Temperature
KA1H0565R	TO-220F-4L	-25°C to +85°C

**BLOCK DIAGRAM**



## ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Drain-source (GND) voltage <sup>(1)</sup>	$V_{DSS}$	650	V
Drain-Gate voltage ( $R_{GS}=1M\Omega$ )	$V_{DGR}$	650	V
Gate-source (GND) voltage	$V_{GS}$	$\pm 30$	V
Drain current pulsed <sup>(2)</sup>	$I_{DM}$	20	$A_{DC}$
Single pulsed avalanche energy <sup>(3)</sup>	$E_{AS}$	230	mJ
Avalanche current <sup>(4)</sup>	$I_{AS}$	–	A
Continuous drain current ( $T_C=25^\circ C$ )	$I_D$	5.0	$A_{DC}$
Continuous drain current ( $T_C=100^\circ C$ )	$I_D$	3.5	$A_{DC}$
Supply voltage	$V_{CC}$	30	V
Analog input voltage range	$V_{FB}$	$-0.3$ to $V_{SD}$	V
Total power dissipation	$P_D$ (watt H/S)	140	W
	Derating	1.11	$W/^\circ C$
Operating temperature	$T_{OPR}$	$-25$ to $+85$	$^\circ C$
Storage temperature	$T_{STG}$	$-55$ to $+150$	$^\circ C$

## NOTES:

- $T_j=25^\circ C$  to  $150^\circ C$
- Repetitive rating: Pulse width limited by maximum junction temperature
- $L=30mH$ ,  $V_{DD}=50V$ ,  $R_G=27\Omega$ , starting  $T_j=25^\circ C$

**ELECTRICAL CHARACTERISTICS (SFET part)**

(Ta=25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
Drain-source breakdown voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=50\mu A$	650	–	–	V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS}=\text{Max.}, \text{Rating}, V_{GS}=0V$	–	–	50	$\mu A$
		$V_{DS}=0.8\text{Max.}, \text{Rating}, V_{GS}=0V, T_C=125^\circ C$	–	–	200	$\mu A$
Static drain-source on resistance <sup>(note)</sup>	$R_{DS(ON)}$	$V_{GS}=10V, I_D=2.5A$	–	1.76	2.2	$\Omega$
Forward transconductance <sup>(note)</sup>	gfs	$V_{DS}=50V, I_D=2.5A$	2.5	–	–	mho
Input capacitance	$C_{iss}$	$V_{GS}=0V, V_{DS}=25V, f=1\text{MHz}$	–	1457	–	$\mu F$
Output capacitance	$C_{oss}$		–	130	–	
Reverse transfer capacitance	$C_{rss}$		–	38.8	–	
Turn on delay time	td(on)	$V_{DD}=0.5BV_{DSS}, I_D=5.0A$ (MOSFET switching time are essentially independent of operating temperature)	–	–	60	nS
Rise time	tr		–	–	150	
Turn off delay time	td(off)		–	–	300	
Fall time	tf		–	–	130	
Total gate charge (gate-source+gate-drain)	Qg	$V_{GS}=10V, I_D=5.0A, V_{DS}=0.5BV_{DSS}$ (MOSFET switching time are essentially independent of operating temperature)	–	–	56	nC
Gate-source charge	Qgs		–	10.3	–	
Gate-drain (Miller) charge	Qgd		–	22.3	–	

**NOTE:** Pulse test: Pulse width  $\leq 300\mu S$ , duty cycle  $\leq 2\%$

**ELECTRICAL CHARACTERISTICS (Control part)**

(Ta=25°C unless otherwise specified)

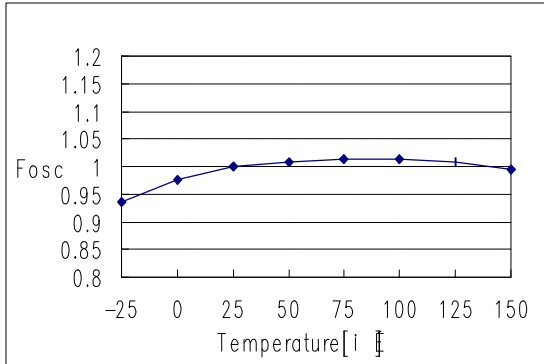
Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
<b>REFERENCE SECTION</b>						
Output voltage <sup>(1)</sup>	V <sub>ref</sub>	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability <sup>(1)(2)</sup>	V <sub>ref</sub> /ΔT	-25°C≤Ta≤+85°C	-	0.3	0.6	mV/°C
<b>OSCILLATOR SECTION</b>						
Initial accuracy	F <sub>OSC</sub>	Ta=25°C	90	100	110	kHz
Frequency change with temperature <sup>(2)</sup>	ΔF/ΔT	-25°C≤Ta≤+85°C	-	±5	±10	%
<b>PWM SECTION</b>						
Maximum duty cycle	D <sub>max</sub>	-	64	67	70	%
<b>FEEDBACK SECTION</b>						
Feedback source current	I <sub>FB</sub>	Ta=25°C, 0V≤V <sub>fb</sub> ≤3V	0.7	0.9	1.1	mA
Shutdown delay current	I <sub>delay</sub>	Ta=25°C, 5V≤V <sub>fb</sub> ≤V <sub>SD</sub>	4.0	5.0	6.0	μA
<b>OVER CURRENT PROTECTION SECTION</b>						
Over current protection	I <sub>L</sub> (max)	Max. inductor current	3.08	3.5	3.92	A
<b>UVLO SECTION</b>						
Start threshold voltage	V <sub>th</sub> (H)	-	14	15	16	V
Minimum operating voltage	V <sub>th</sub> (L)	After turn on	9	10	11	V
<b>TOTAL STANDBY CURRENT SECTION</b>						
Start current	I <sub>ST</sub>	V <sub>CC</sub> =14V	0.1	0.3	0.45	mA
Operating supply current (control part only)	I <sub>OPR</sub>	Ta=25°C	6	12	18	mA
V <sub>CC</sub> zener voltage	V <sub>Z</sub>	I <sub>CC</sub> =20mA	30	32.5	35	V
<b>SHUTDOWN SECTION</b>						
Shutdown Feedback voltage	V <sub>SD</sub>	-	6.9	7.5	8.1	V
Thermal shutdown temperature (T <sub>j</sub> ) <sup>(1)</sup>	T <sub>SD</sub>	-	140	160	-	°C
Over voltage protection voltage	V <sub>OVp</sub>	-	23	25	28	V

**NOTES:**

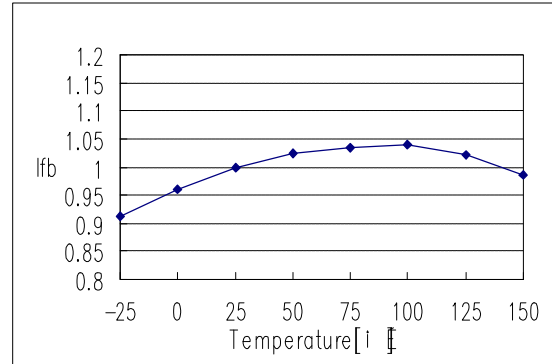
1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS (wafer test) process

## TYPICAL PERFORMANCE CHARACTERISTICS

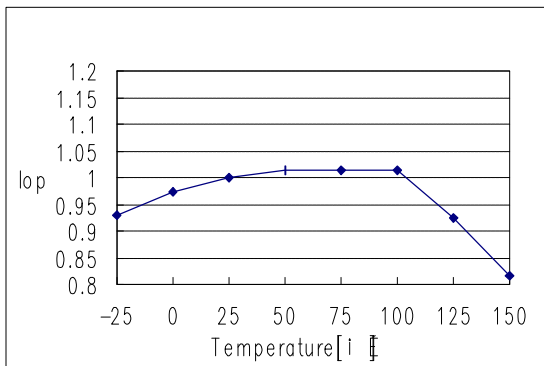
(These characteristic graphs are normalized at  $T_a=25^\circ\text{C}$ )



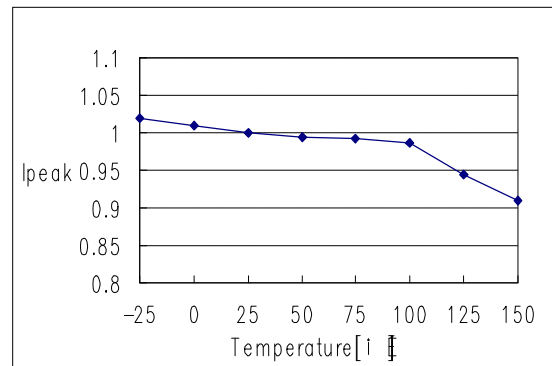
**Figure 1. Operating Frequency**



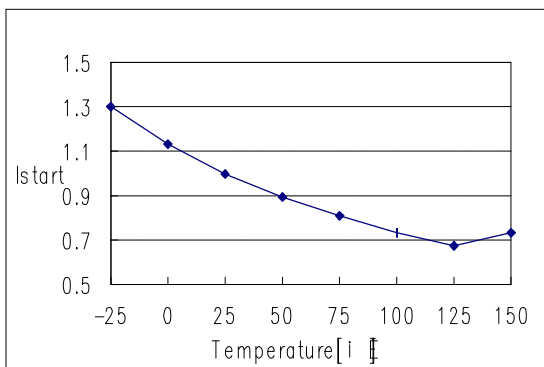
**Figure 2. Feedback Source Current**



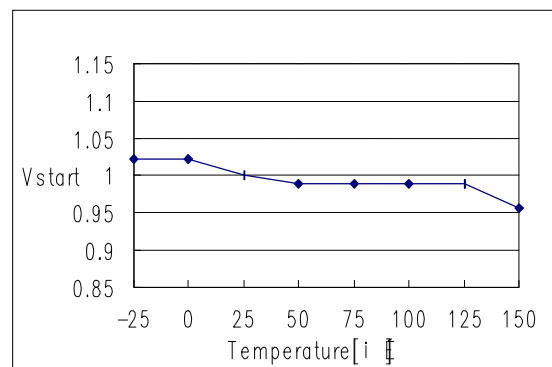
**Figure 3. Operating Current**



**Figure 4. Max. Inductor Current**



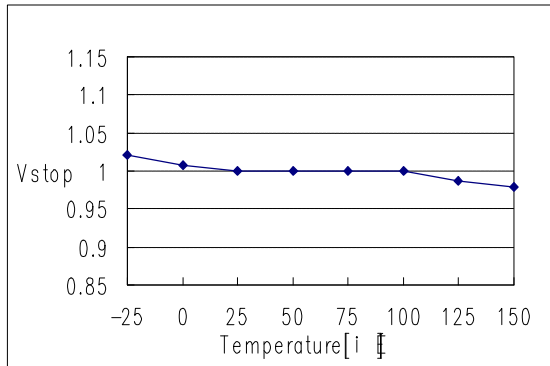
**Figure 5. Start up Current**



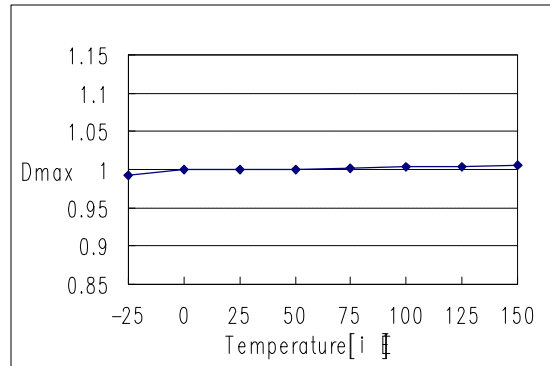
**Figure 6. Start Threshold Voltage**

**TYPICAL PERFORMANCE CHARACTERISTICS (Continued)**

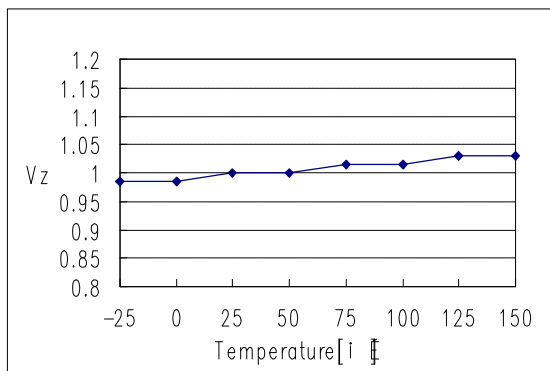
(These characteristic graphs are normalized at  $T_a=25^{\circ}\text{C}$ )



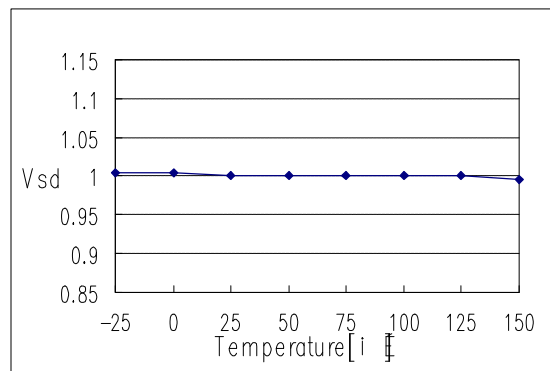
**Figure 7. Stop Threshold Voltage**



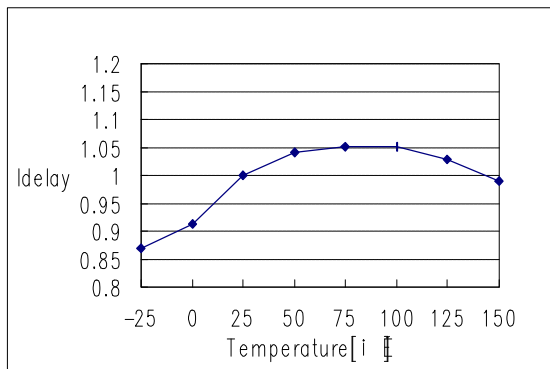
**Figure 8. Maximum Duty Cycle**



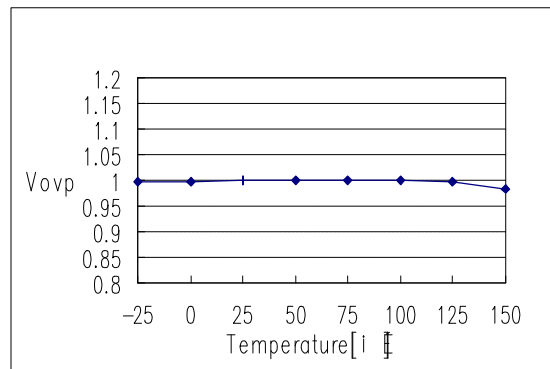
**Figure 9. V<sub>CC</sub> Zener Voltage**



**Figure 10. Shutdown Feedback Voltage**



**Figure 11. Shutdown Delay Current**



**Figure 12. Over Voltage Protection**

### TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(These characteristic graphs are normalized at Ta=25°C)

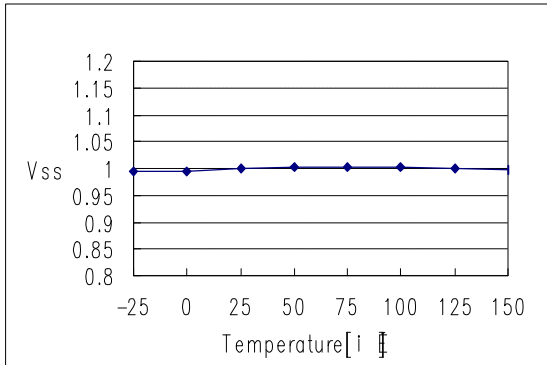


Figure 13. Soft Start Voltage

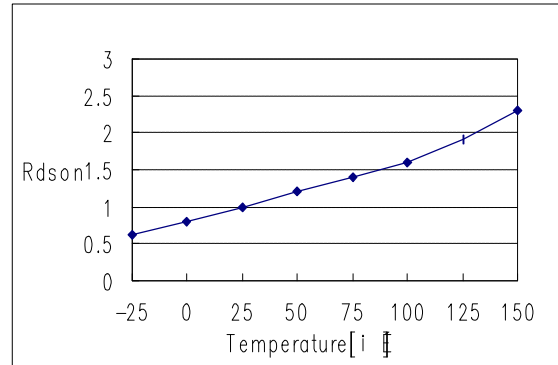


Figure 14. Drain Source Turn-on Resistance

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